

2SK1605

Silicon N-Channel Power F-MOS FET

■ Features

- High avalanche energy capacity
- V_{GS} : 30V guaranteed
- Low $R_{DS(on)}$, high-speed switching characteristic

■ Applications

- High-speed switching (switching power supply)
- For high-frequency power amplification

■ Absolute Maximum Ratings ($T_C = 25^\circ\text{C}$)

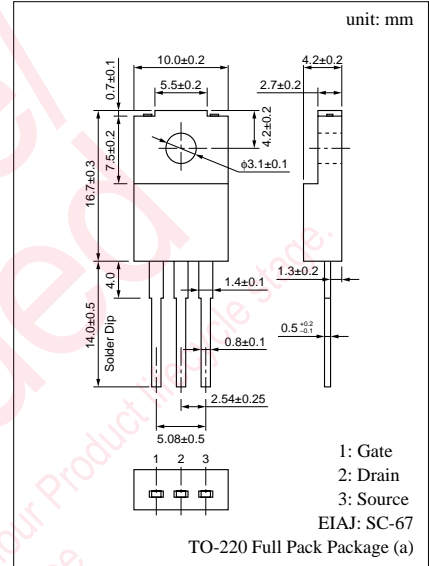
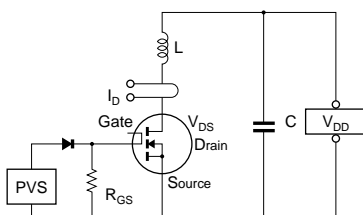
Parameter	Symbol	Rated	Unit
Drain to Source breakdown voltage	V_{DSS}	450	V
Gate to Source voltage	V_{GSS}	± 30	V
Drain current	DC	I_D	± 5
	Pulse	I_{DP}	± 10
Avalanche energy capacity	EAS*	100	mJ
Allowable power dissipation	$T_C = 25^\circ\text{C}$	P_D	50
	$T_a = 25^\circ\text{C}$		2
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

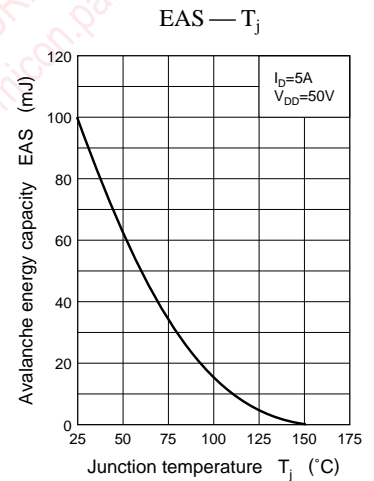
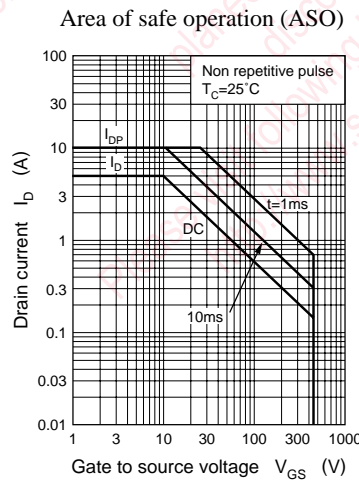
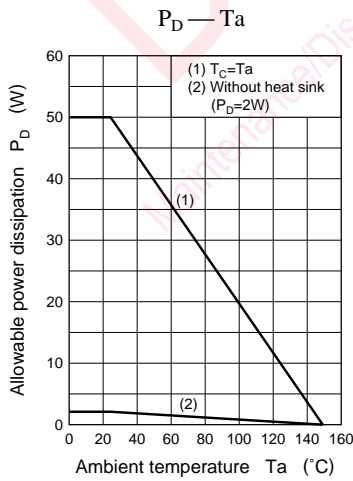
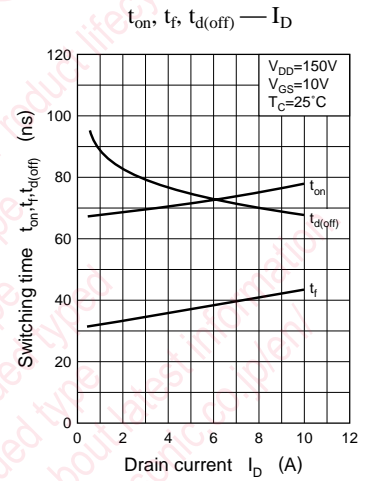
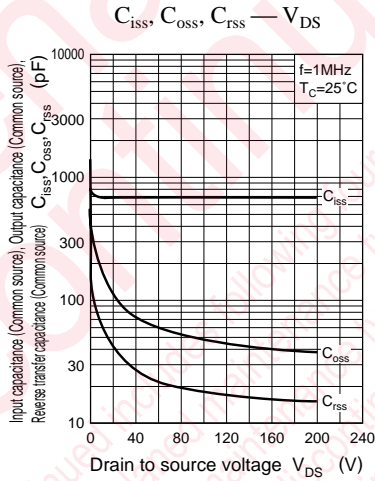
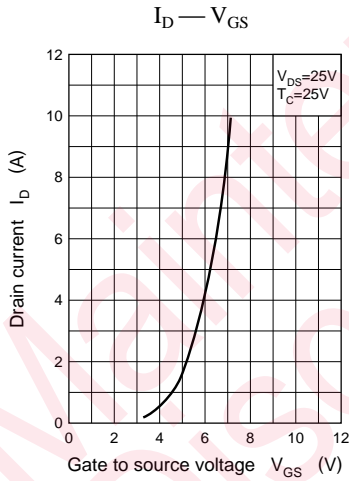
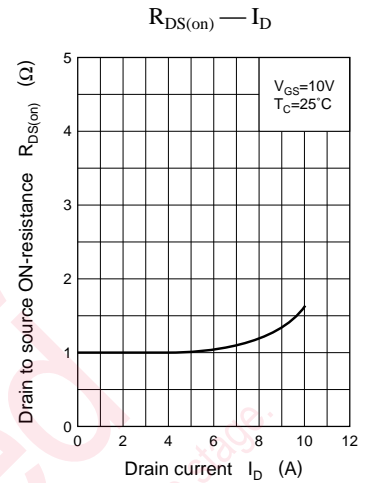
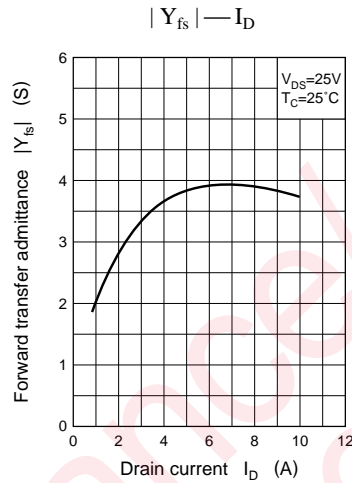
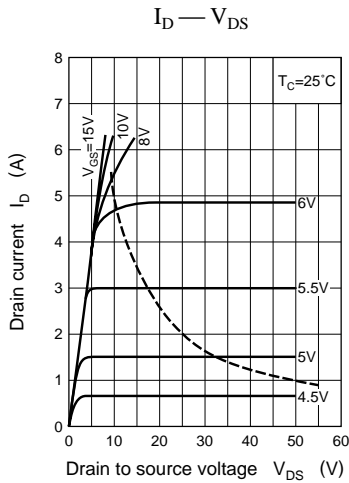
* Single pulse

■ Electrical Characteristics ($T_C = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	I_{DSS}	$V_{DS} = 360\text{V}$, $V_{GS} = 0$			0.1	mA
Gate to Source leakage current	I_{GSS}	$V_{GS} = \pm 30\text{V}$, $V_{DS} = 0$			± 1	μA
Drain to Source breakdown voltage	V_{DSS}	$I_D = 1\text{mA}$, $V_{GS} = 0$	450			V
Avalanche energy capacity	EAS*	$L = 8\text{mH}$, $I_D = 5\text{A}$, $V_{DD} = 50\text{V}$	100			mJ
Gate threshold voltage	V_{th}	$V_{DS} = 25\text{V}$, $I_D = 1\text{mA}$	1		5	V
Drain to Source ON-resistance	$R_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 3\text{A}$		1	1.3	Ω
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 25\text{V}$, $I_D = 3\text{A}$	2	3.2		S
Input capacitance (Common Source)	C_{iss}	$V_{DS} = 20\text{V}$, $V_{GS} = 0$, $f = 1\text{MHz}$		700		pF
Output capacitance (Common Source)	C_{oss}			100		pF
Reverse transfer capacitance (Common Source)	C_{rss}			40		pF
Turn-on time	t_{on}		$V_{GS} = 10\text{V}$, $I_D = 3\text{A}$ $V_{DD} = 150\text{V}$, $R_L = 50\Omega$		70	
Fall time	t_f			35		ns
Turn-off time (delay time)	$t_{d(off)}$			80		ns

* Avalanche energy capacity test circuit





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